

**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc	
Collector 1 to Collector 2 Voltage Voltage Rating and Lead to Case	V <sub>C1C2</sub>	±200 ±200	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc	
Base Current	I <sub>B</sub>	10	mAdc	
Collector Current — Continuous	I <sub>C</sub>	50	mAdc	
		One Die	Both Die	
Total Device Dissipation @ T <sub>A</sub> = 25°C — Ceramic Metal Can	P <sub>D</sub>	250 500	350 600	mW mW/°C
Derate above 25°C — Ceramic Metal Can		1.5 2.9	2.0 3.4	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C Metal Can	P <sub>D</sub>	1.2 6.85	2.0 11.42	Watts mW/°C
Operating and Storage Junction Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-65 to +200	

# 2N4937 thru 2N4942

2N4937, 2N4938, 2N4939  
CASE 654-07, STYLE 1  
2N4440, 2N4441, 2N4442  
CASE 610A-04, STYLE 1

**DUAL  
AMPLIFIER TRANSISTOR**

PNP SILICON

Refer to MD3250,A for graphs.

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**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)**

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	40	—	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	50	—	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	5.0	—	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 40 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	—	20	nAdc
Emitter Cutoff Current (V <sub>BE</sub> = 3.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	—	20	nAdc

**ON CHARACTERISTICS**

DC Current Gain (I <sub>C</sub> = 100 μAdc, V <sub>CE</sub> = 10 Vdc) (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc)	h <sub>FE</sub>	40 50 50	200 250 250	—
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**SMALL-SIGNAL CHARACTERISTICS**

Current-Gain — Bandwidth Product (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)	f <sub>T</sub>	300	900	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 140 kHz) Emitter Guarded	C <sub>cb</sub>	—	5.0	pF
Input Impedance (I <sub>BE</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 140 kHz) Collector Guarded	C <sub>eb</sub>	—	10	pF
Input Impedance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	h <sub>ie</sub>	1.0	10	kΩ
Voltage Feedback Ratio (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	h <sub>re</sub>	—	10	X 10 <sup>-4</sup>
Small-Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	h <sub>fe</sub>	50	—	—
Output Admittance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	h <sub>oe</sub>	5.0	50	μmhos
Noise Figure (I <sub>C</sub> = 100 μAdc, V <sub>CE</sub> = 10 Vdc, R <sub>S</sub> = 3.0 kΩ, f = 10 Hz to 15.7 kHz)	NF	—	4.0	dB

**2N4937 thru 2N4942**

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted.)

Characteristic		Symbol	Min	Max	Unit
<b>MATCHING CHARACTERISTICS</b>					
DC Current Gain Ratio(1) ( $I_C = 100 \mu\text{A}$ dc to 1.0 mA dc, $V_{CE} = 10 \text{ Vdc}$ )	2N4937, 2N4941	$h_{FE1}/h_{FE2}$	0.9	1.0	—
	2N4938, 2N4940		0.8	1.0	
( $I_C = 100 \mu\text{A}$ dc to 1.0 mA dc, $V_{CE} = 10 \text{ Vdc}$ , $T_A = -55^\circ\text{C}$ to $125^\circ\text{C}$ )	2N4937, 2N4941		0.85	1.0	
	2N4938, 2N4940		0.7	1.0	
Base-Emitter Voltage Differential ( $I_C = 100 \mu\text{A}$ dc to 1.0 mA dc, $V_{CE} = 10 \text{ Vdc}$ )	2N4937, 2N4941	$ V_{BE1} - V_{BE2} $	—	3.0	mVdc
	2N4938, 2N4940		—	5.0	
Base-Emitter Voltage Differential Gradient ( $I_C = 100 \mu\text{A}$ dc to 1.0 mA dc, $V_{CE} = 10 \text{ Vdc}$ , $T_A = 25^\circ\text{C}$ to $+125^\circ\text{C}$ )	2N4937, 2N4941	$\frac{\Delta(V_{BE1} - V_{BE2})}{\Delta T_A}$	—	1.0	mVdc
	2N4938, 2N4940		—	2.0	
( $I_C = 100 \mu\text{A}$ dc to 1.0 mA dc, $V_{CE} = 10 \text{ Vdc}$ , $T_A = -55^\circ\text{C}$ to $25^\circ\text{C}$ )	2N4937, 2N4941		—	0.8	
	2N4938, 2N4940		—	1.6	

(1) The lowest  $h_{FE}$  reading is taken as  $h_{FE1}$  for this ratio.